

INTRODUCE:

HVGT high voltage silicon rectifier assembly is made of high quality glass passivated chip and high reliability epoxy resin sealing structure, and through professional testing equipment inspection qualified after to customers.

FEATURES:

1. High reliability design.
2. High voltage design.
3. High current .
4. Conform to RoHS and SGS.
5. Epoxy resin molded in vacuumHave anticorrosion in the surface.

APPLICATIONS:

1. High voltage multiplier circuit
2. High voltage test equipment circuit .
3. General purpose high voltage rectifier.
4. Environmental desulfurization system.

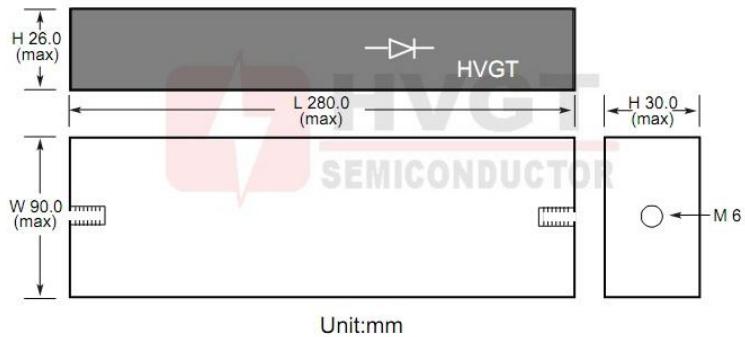
MECHANICAL DATA:

1. Case: epoxy resin molding.
2. Terminal: screw holes.
3. Net weight: 1050 grams (approx).

SHAPE DISPLAY:

SIZE: (Unit:mm)
HVGT NAME: HVC-289030
HVC-289030 Series

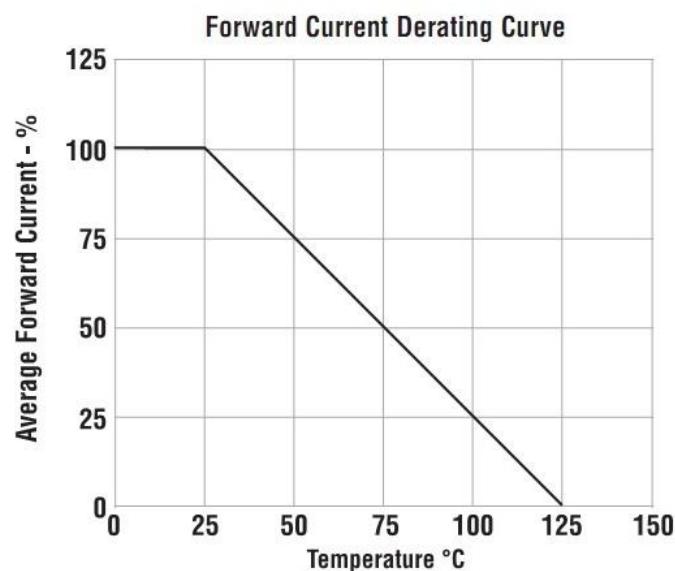
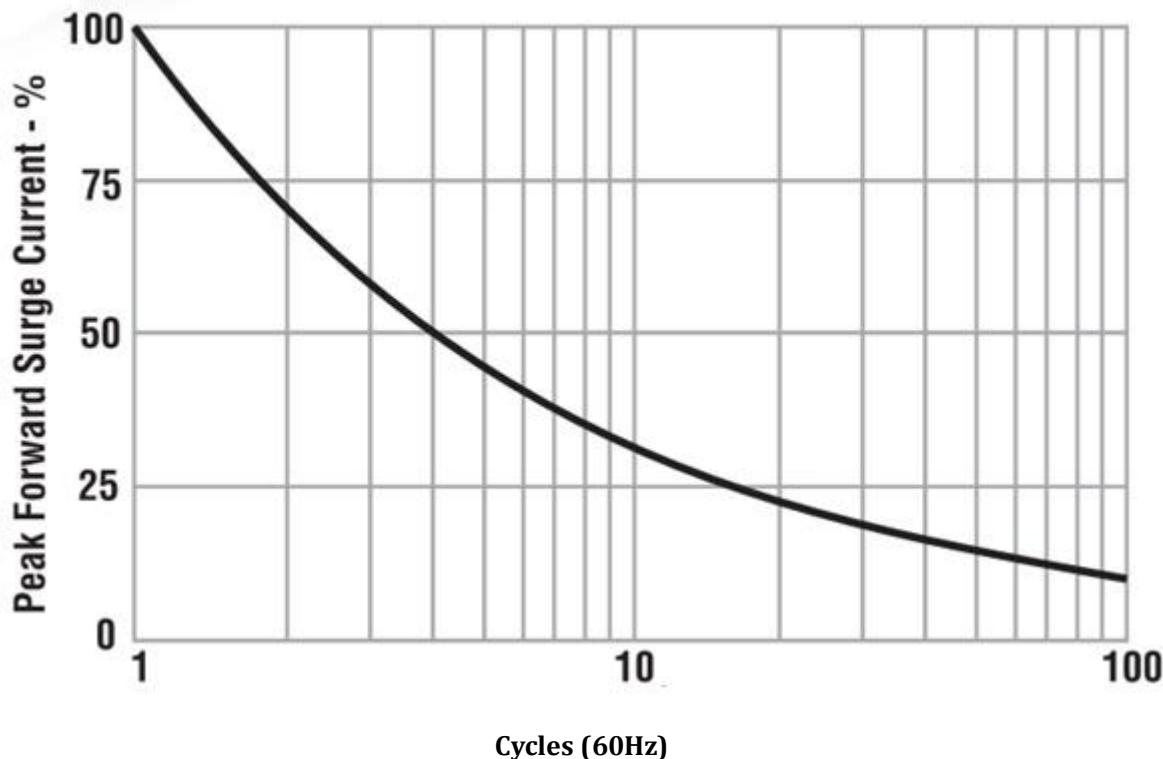
Screw Holes M6


MAXIMUM RATINGS AND CHARACTERISTICS: (Absolute Maximum Ratings)

| Items | Symbols | Condition | Data Value | Units |
|--------------------------------------|-------------------|--|------------|-------|
| Repetitive Peak Reverse Voltage | V _{RRM} | T _A =25°C | 200 | kV |
| Non-Repetitive Peak Reverse Voltage | V _{RSM} | T _A =25°C | 240 | kV |
| Average Forward Current Maximum | I _{FAVM} | T _A =25°C | 3.0 | A |
| | | T _{OIL} =55°C | -- | A |
| Non-Repetitive Forward Surge Current | I _{FSM} | T _A =25°C; 60Hz Half-Sine Wave; 8.3mS | 60 | A |
| Junction Temperature | T _J | | 125 | °C |
| Allowable Operation Case Temperature | T _c | | -40~+125 | °C |
| Storage Temperature | T _{STG} | | -40~+150 | °C |

ELECTRICAL CHARACTERISTICS: T_A=25°C (Unless Otherwise Specified)

| Items | Symbols | Condition | Data value | Units |
|-------------------------------|-----------------|--|------------|-------|
| Maximum Forward Voltage Drop | V _{FM} | at 25°C; at I _{FAVM} | 240 | V |
| Maximum Reverse Current | I _{R1} | at 25°C; at V _{RRM} | 5.0 | uA |
| | I _{R2} | at 100°C; at V _{RRM} | 50 | uA |
| Maximum Reverse Recovery Time | T _{RR} | at 25°C; I _F =0.5I _R ; I _R =I _{FAVM} ; I _{RR} =0.25I _R | -- | nS |
| Junction Capacitance | C _J | at 25°C; V _R =0V; f=1MHz | -- | pF |

Fig 1
Forward Current Derating Curve

Fig 2
Non-Repetitive Surge Current

Marking
Type
Code
Cathode Mark

2CL200KV/3A

 2CL200KV/3A
 HVGT